

Ultra Low Capacitance ESD Protection Diode

DESCRIPTION

HESD03D6BU is a low-capacitance Transient Voltage Suppressor (TVS) designed to provide electrostatic discharge (ESD) protection for high-speed data interfaces. With typical capacitance of 0.25pF. HESD03D6BU designed to protect parasitic-sensitive systems against over-voltage and over-current transient events. It complies with IEC 61000-4-2 (ESD), Level 4 (±15kV air, ±8kV contact discharge), IEC 61000-4-4 (electrical fast transient - EFT) (40A, 5/50 ns), very fast charged device model (CDM) ESD and cable discharge event (CDE), etc.

HESD03D6BU uses ultra-small DFN0603 package. Each HESD03D6BU device can protect one high-speed data line. It offers system designers flexibility to protect single data line where space is a premium concern. The combined features of low capacitance, ultra-small size and high **ESD** robustness make HESD03D6BU ideal for high-speed data port and high-frequency line applications, such as cellular phones and HD visual devices.

ORDERING INFORMATION

Device: HESD03D6BUPackage: DFN0603Marking: 3BU

→ Material: Halogen free→ Packing: Tape & Reel

♦ Quantity per reel: 10,000pcs

PIN CONFIGURATION



FEATURES

♦ Transient protection for high-speed data lines IEC 61000-4-2 (ESD) ±15kV (Air) ±8kV (Contact)

IEC 61000-4-4 (EFT) 40A (5/50 ns) Cable Discharge Event (CDE)

- ♦ Package optimized for high-speed lines
- ♦Ultra-small package (0.6mm×0.3mm×0.3mm)
- ♦Protects one data, control line
- ♦Low capacitance: 0.25pF (Typical)
- ♦Low leakage current
- ♦Low clamping voltage

MACHANICAL DATA

♦DFN0603 package

♦ Flammability Rating: UL 94V-0

♦Packaging: Tape and Reel

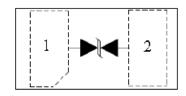
♦ High temperature soldering guaranted: 260 °C/10s

♦Reel size: 7 inch

APPLICATIONS

- ♦ Serial ATA
- ♦ Desktops, Servers and Notebooks
- ♦ Cellular Phones
- **♦MDDI** Ports
- ♦USB Data Line Protection
- ♦ Display Ports
- ♦ Digital Visual Interfaces (DVI)

CIRCUIT DIAGRAM





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ABSOLUTE MAXIMUM RATING

Symbol	Parameter	Value	Units	
V _{ESD}	ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	±20 ±20	kV	
P _{PP}	Peak Pulse Power (8/20μs)	96	W	
T _{OPT}	Operating Temperature	-55~125	°C	
T _{STG}	Storage Temperature	-55~150	°C	

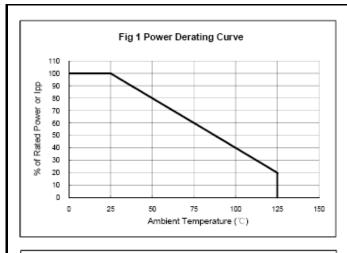
ELECTRICAL CHARACTERISTICS (Tamb=25°C)

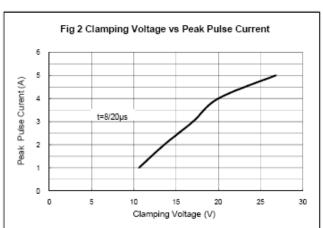
Symbol	Parameter	Test Condition	Min	Тур	Max	Units
V_{RWM}	Reverse Working Voltage				3.3	V
V_{BR}	Reverse Breakdown Voltage	I _T = 1mA	4.2			V
I _R	Reverse Leakage Current	V _{RWM} = 3.3V			100	nA
Vc	Clamping Voltage	$I_{PP} = 1A, t_p = 8/20 \mu s$			12	V
		$I_{PP} = 4A, t_p = 8/20 \mu s$			24	V
CJ	Junction Capacitance	V _R = 0V, f = 1MHz		0.25		pF

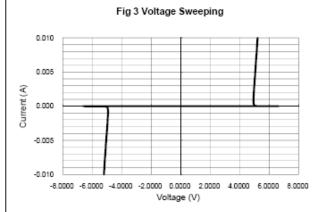


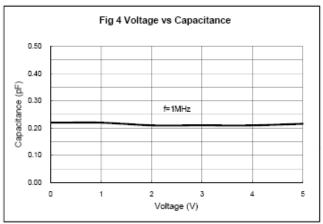
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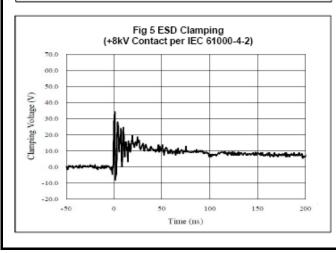
ELECTRICAL CHARACTERISTICS CURVE

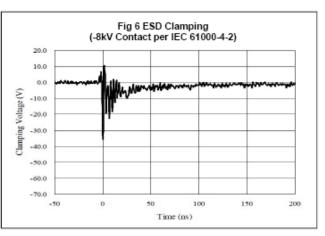














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DFN0603 PACKAGE OUTLINE DIMENSIONS

